



3.3V CMOS 16-BIT UNIVERSAL BUS DRIVER WITH 3-STATE OUTPUTS AND BUS-HOLD

IDT74ALVCH16334

FEATURES:

- 0.5 MICRON CMOS Technology
- Typical $t_{sk(0)}$ (Output Skew) < 250ps
- ESD > 2000V per MIL-STD-883, Method 3015;
> 200V using machine model ($C = 200\text{pF}$, $R = 0$)
- 0.635mm pitch SSOP, 0.50mm pitch TSSOP,
and 0.40mm pitch TVSOP packages
- Extended commercial range of -40°C to $+85^\circ\text{C}$
- $V_{cc} = 3.3\text{V} \pm 0.3\text{V}$, Normal Range
- $V_{cc} = 2.7\text{V}$ to 3.6V , Extended Range
- $V_{cc} = 2.5\text{V} \pm 0.2\text{V}$
- CMOS power levels ($0.4\mu\text{W}$ typ. static)
- Rail-to-Rail output swing for increased noise margin

Drive Features for ALVCH16334:

- High Output Drivers: $\pm 24\text{mA}$
- Suitable for heavy loads

APPLICATIONS:

- SDRAM Modules
- PC Motherboards
- Workstations

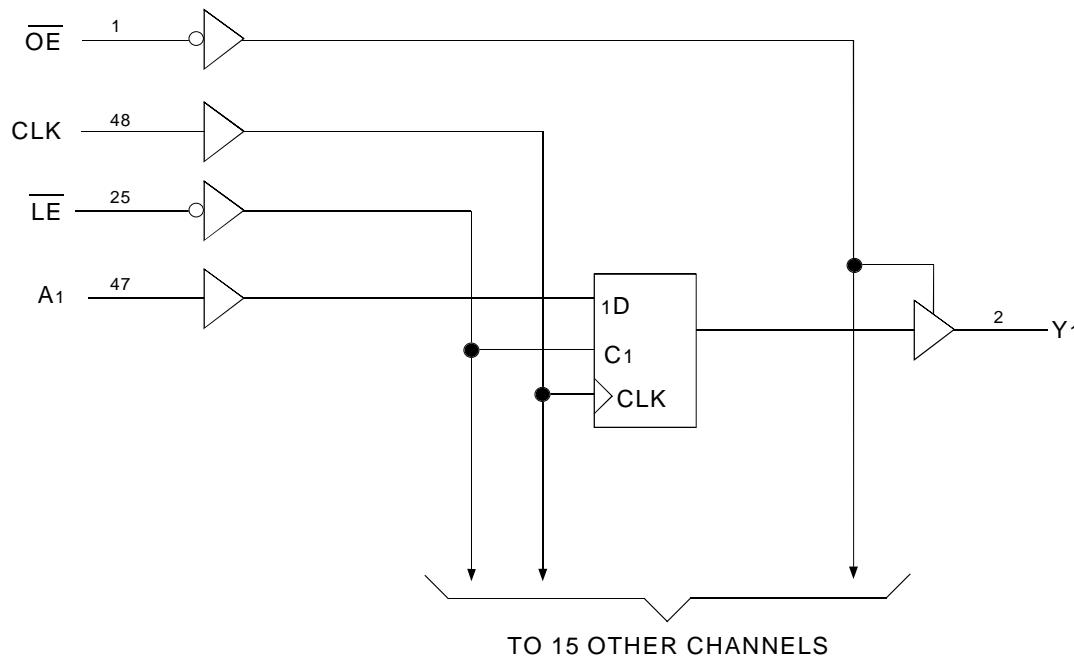
DESCRIPTION:

This 16-bit universal bus driver is built using advanced dual metal CMOS technology. Data flow from A to Y is controlled by the output-enable (\overline{OE}) input. The device operates in the transparent mode when the latch-enable (\overline{LE}) input is low. When \overline{LE} is high, the A data is latched if the clock (CLK) input is held at a high or low logic level. If \overline{LE} is high, the A data is stored in the latch/flip-flop on the low-to-high transition of CLK. When \overline{OE} is high, the outputs are in the high-impedance state.

The ALVCH16334 has been designed with a $\pm 24\text{mA}$ output driver. This driver is capable of driving a moderate to heavy load while maintaining speed performance.

The ALVCH16334 has "bus-hold" which retains the inputs' last state whenever the input bus goes to a high impedance. This prevents floating inputs and eliminates the need for pull-up/down resistors.

Functional Block Diagram



EXTENDED COMMERCIAL TEMPERATURE RANGE

APRIL 1999

PIN CONFIGURATION

\overline{OE}	1	48	CLK
Y ₁	2	47	A ₁
Y ₂	3	46	A ₂
GND	4	45	GND
Y ₃	5	44	A ₃
Y ₄	6	43	A ₄
V _{CC}	7	42	V _{CC}
Y ₅	8	41	A ₅
Y ₆	9	40	A ₆
GND	10	39	GND
Y ₇	11	SO48-1	A ₇
		SO48-2	
Y ₈	12	SO48-3	A ₈
Y ₉	13		A ₉
Y ₁₀	14		A ₁₀
GND	15	34	GND
Y ₁₁	16	33	A ₁₁
Y ₁₂	17	32	A ₁₂
V _{CC}	18	31	V _{CC}
Y ₁₃	19	30	A ₁₃
Y ₁₄	20	29	A ₁₄
GND	21	28	GND
Y ₁₅	22	27	A ₁₅
Y ₁₆	23	26	A ₁₆
NC	24	25	LE

SSOP/TSSOP/TVSOP
TOP VIEW

PIN DESCRIPTION

Pin Names	Description
\overline{OE}	3-State Output Enable Inputs (Active LOW)
CLK	Register Input Clock
\overline{LE}	Latch Enable (Transparent LOW)
A _x	Data Inputs ⁽¹⁾
Y _x	3-State Outputs

NOTE:

- These pins have "Bus-Hold." All other pins are standard inputs, outputs, or I/Os.

ABSOLUTE MAXIMUM RATING (1)

Symbol	Description	Max.	Unit
V _{TERM} ⁽²⁾	Terminal Voltage with Respect to GND	-0.5 to + 4.6	V
V _{TERM} ⁽³⁾	Terminal Voltage with Respect to GND	-0.5 to V _{CC} + 0.5	V
T _{STG}	Storage Temperature	-65 to + 150	°C
I _{OUT}	DC Output Current	-50 to + 50	mA
I _{IK}	Continuous Clamp Current, V _I < 0 or V _I > V _{CC}	± 50	mA
I _{OK}	Continuous Clamp Current, V _O < 0	-50	mA
I _{CC}	Continuous Current through each V _{CC} or GND	±100	mA
I _{SS}			

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NOTES:

- Stresses greater than those listed under ABSOLUTE MAXIMUM RATINGS may cause permanent damage to the device. This is a stress rating only and functional operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect reliability.
- V_{CC} terminals.
- All terminals except V_{CC}.

CAPACITANCE (T_A = +25°C, f = 1.0MHz)

Symbol	Parameter ⁽¹⁾	Conditions	Typ.	Max.	Unit
C _{IN}	Input Capacitance	V _{IN} = 0V	5	7	pF
C _{OUT}	Output Capacitance	V _{OUT} = 0V	7	9	pF
C _{I/O}	I/O Port Capacitance	V _{IN} = 0V	7	9	pF

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NOTE:

- As applicable to the device type.

FUNCTION TABLE (1)

Inputs				Output
\overline{OE}	\overline{LE}	CLK	A _x	Y _x
H	X	X	X	Z
L	L	X	L	L
L	L	X	H	H
L	H	↑	L	L
L	H	↑	H	H
L	H	L or H	X	Y _x ⁽²⁾

NOTES:

- H = HIGH Voltage Level
L = LOW Voltage Level
X = Don't Care
Z = High-Impedance
↑ = LOW-to-HIGH Transition
- Output level before the indicated steady-state input conditions were established.

DC ELECTRICAL CHARACTERISTICS OVER OPERATING RANGE

Following Conditions Apply Unless Otherwise Specified:

Operating Condition: TA = -40°C to +85°C

Symbol	Parameter	Test Conditions		Min.	Typ. ⁽¹⁾	Max.	Unit
VIH	Input HIGH Voltage Level	Vcc = 2.3V to 2.7V		1.7	—	—	V
		Vcc = 2.7V to 3.6V		2	—	—	
VIL	Input LOW Voltage Level	Vcc = 2.3V to 2.7V		—	—	0.7	V
		Vcc = 2.7V to 3.6V		—	—	0.8	
I _{IH}	Input HIGH Current	Vcc = 3.6V	Vi = Vcc	—	—	± 5	µA
I _{IL}	Input LOW Current	Vcc = 3.6V	Vi = GND	—	—	± 5	
I _{OZH}	High Impedance Output Current (3-State Output pins)	Vcc = 3.6V	Vo = Vcc	—	—	± 10	µA
I _{OZL}			Vo = GND	—	—	± 10	µA
V _{IK}	Clamp Diode Voltage	Vcc = 2.3V, I _{IN} = -18mA		—	-0.7	-1.2	V
V _H	Input Hysteresis	Vcc = 3.3V		—	100	—	mV
I _{CCL} I _{CCH} I _{CCZ}	Quiescent Power Supply Current	Vcc = 3.6V VIN = GND or Vcc		—	0.1	40	µA
ΔI _{CC}	Quiescent Power Supply Current Variation	One input at Vcc - 0.6V, other inputs at Vcc or GND		—	—	750	µA

NOTE:

1. Typical values are at Vcc = 3.3V, +25°C ambient.

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BUS-HOLD CHARACTERISTICS

Symbol	Parameter ⁽¹⁾	Test Conditions		Min.	Typ. ⁽²⁾	Max.	Unit
I _{BHH} I _{BHL}	Bus-Hold Input Sustain Current	Vcc = 3.0V	Vi = 2.0V	-75	—	—	µA
			Vi = 0.8V	75	—	—	
I _{BHH} I _{BHL}	Bus-Hold Input Sustain Current	Vcc = 2.3V	Vi = 1.7V	-45	—	—	µA
			Vi = 0.7V	45	—	—	
I _{BHHO} I _{BHLO}	Bus-Hold Input Overdrive Current	Vcc = 3.6V	Vi = 0 to 3.6V	—	—	± 500	µA

NOTES:

1. Pins with Bus-hold are identified in the pin description.
2. Typical values are at Vcc = 3.3V, +25°C ambient.

OUTPUT DRIVE CHARACTERISTICS

Symbol	Parameter	Test Conditions ⁽¹⁾		Min.	Max.	Unit
VOH	Output HIGH Voltage	VCC = 2.3V to 3.6V	I _{OH} = - 0.1mA	VCC - 0.2	—	V
		VCC = 2.3V	I _{OH} = - 6mA	2	—	
		VCC = 2.3V	I _{OH} = - 12mA	1.7	—	
		VCC = 2.7V		2.2	—	
		VCC = 3.0V		2.4	—	
		VCC = 3.0V	I _{OH} = - 24mA	2	—	
VOL	Output LOW Voltage	VCC = 2.3V to 3.6V	I _{OL} = 0.1mA	—	0.2	V
		VCC = 2.3V	I _{OL} = 6mA	—	0.4	
			I _{OL} = 12mA	—	0.7	
		VCC = 2.7V	I _{OL} = 12mA	—	0.4	
		VCC = 3.0V	I _{OL} = 24mA	—	0.55	

NOTE:

1. V_{IH} and V_{IL} must be within the min. or max. range shown in the DC ELECTRICAL CHARACTERISTICS OVER OPERATING RANGE table for the appropriate V_{cc} range. T_A = - 40°C to + 85°C.

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OPERATING CHARACTERISTICS, T_A = 25°C

Symbol	Parameter	Test Conditions	V _{cc} = 2.5V ± 0.2V	V _{cc} = 3.3V ± 0.3V	Unit
			Typical	Typical	
CPD	Power Dissipation Capacitance Outputs enabled	C _L = 0pF, f = 10Mhz	32	37	pF
	Power Dissipation Capacitance Outputs disabled		7	11	

SWITCHING CHARACTERISTICS⁽¹⁾

Symbol	Parameter	V _{CC} = 2.5V ± 0.2V		V _{CC} = 2.7V		V _{CC} = 3.3V ± 0.3V		Unit
		Min.	Max.	Min.	Max.	Min.	Max.	
f _{MAX}		150	—	150	—	150	—	MHz
t _{PLH} t _{PHL}	Propagation Delay Ax to Yx	1	3.7	—	3.6	1.1	3.3	ns
t _{PLH} t _{PHL}	Propagation Delay LE to Yx	1	4.8	—	5	1.3	4.4	ns
t _{PLH} t _{PHL}	Propagation Delay CLK to Yx	1	4.4	—	4.5	1	4.1	ns
t _{PZH} t _{PZL}	Output Enable Time OE to Yx	1	5.4	—	5.4	1.1	4.6	ns
t _{PHZ} t _{PLZ}	Output Disable Time OE to Yx	1	4.1	—	4.5	1.7	4.4	ns
t _w	Pulse Duration, LE LOW	3.3	—	3.3	—	3.3	—	ns
t _w	Pulse Duration, CLK HIGH or LOW	3.3	—	3.3	—	3.3	—	ns
t _{su}	Setup Time, data before CLK↑	1.4	—	1.7	—	1.5	—	ns
t _{su}	Setup Time, data before LE↑, CLK HIGH	1.2	—	1.6	—	1.3	—	ns
t _{su}	Setup Time, data before LE↑, CLK LOW	1.4	—	1.5	—	1.2	—	ns
t _h	Hold Time, data after CLK↑	0.9	—	0.8	—	0.9	—	ns
t _h	Hold Time, data after LE↑, CLK HIGH or LOW	1.2	—	1.1	—	1.1	—	ns
t _{sk(o)}	Output Skew ⁽²⁾	—	—	—	—	—	500	ps

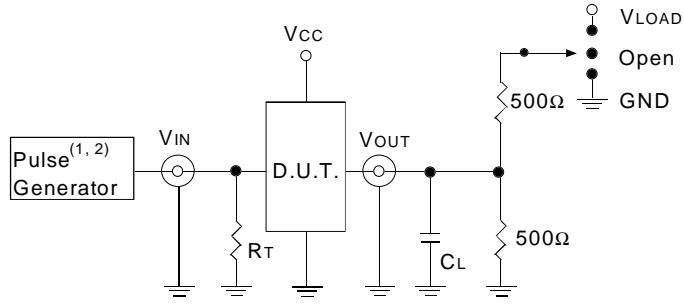
NOTES:

1. See test circuits and waveforms. T_A = -40°C to +85°C.
2. Skew between any two outputs of the same package and switching in the same direction.

TEST CIRCUITS AND WAVEFORMS:**TEST CONDITIONS**

Symbol	$V_{CC(1)} = 3.3V \pm 0.3V$	$V_{CC(1)} = 2.7V$	$V_{CC(2)} = 2.5V \pm 0.2V$	Unit
V_{LOAD}	6	6	$2 \times V_{CC}$	V
V_{IH}	2.7	2.7	V_{CC}	V
V_T	1.5	1.5	$V_{CC}/2$	V
V_{LZ}	300	300	150	mV
V_{HZ}	300	300	150	mV
C_L	50	50	30	pF

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TEST CIRCUITS FOR ALL OUTPUTS**DEFINITIONS:**

- C_L = Load capacitance: includes jig and probe capacitance.
 R_T = Termination resistance: should be equal to Z_{OUT} of the Pulse Generator.

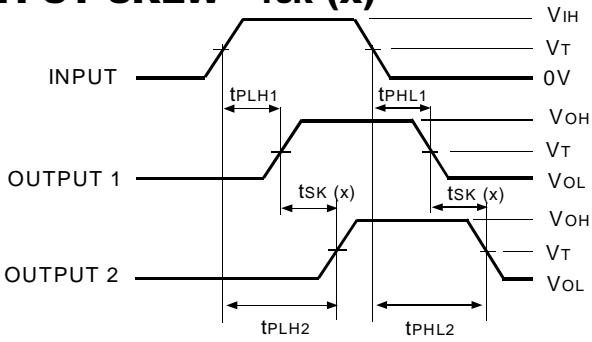
NOTES:

1. Pulse Generator for All Pulses: Rate $\leq 10MHz$; $t_f \leq 2.5ns$; $t_r \leq 2.5ns$.
2. Pulse Generator for All Pulses: Rate $\leq 10MHz$; $t_f \leq 2ns$; $t_r \leq 2ns$.

SWITCH POSITION

Test	Switch
Open Drain	V_{LOAD}
Disable Low	
Enable Low	
Disable High	GND
Enable High	
All Other tests	Open

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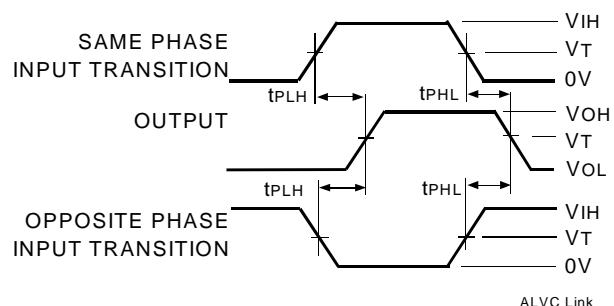
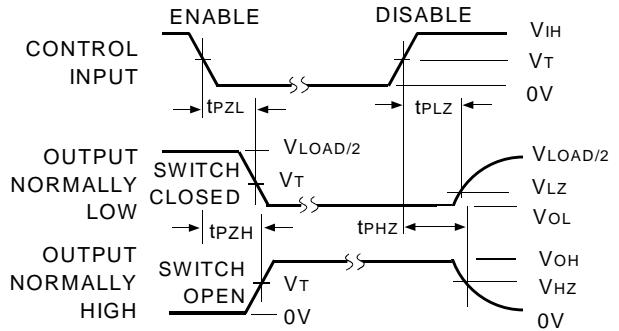
OUTPUT SKEW - $tsk(x)$ 

$$tsk(x) = |tPLH2 - tPLH1| \text{ or } |tPHL2 - tPHL1|$$

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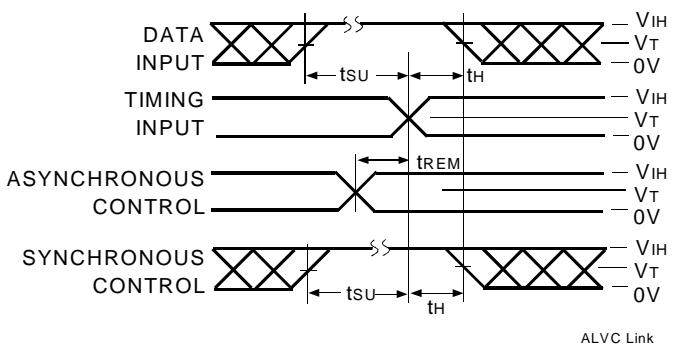
NOTES:

1. For $tsk(o)$ OUTPUT1 and OUTPUT2 are any two outputs.
2. For $tsk(b)$ OUTPUT1 and OUTPUT2 are in the same bank.

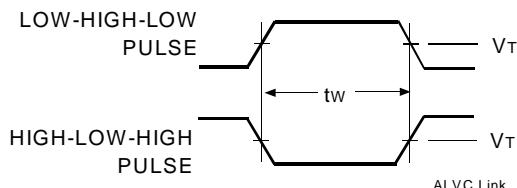
PROPAGATION DELAY**ENABLE AND DISABLE TIMES****NOTE:**

1. Diagram shown for input Control Enable-LOW and input Control Disable-HIGH.

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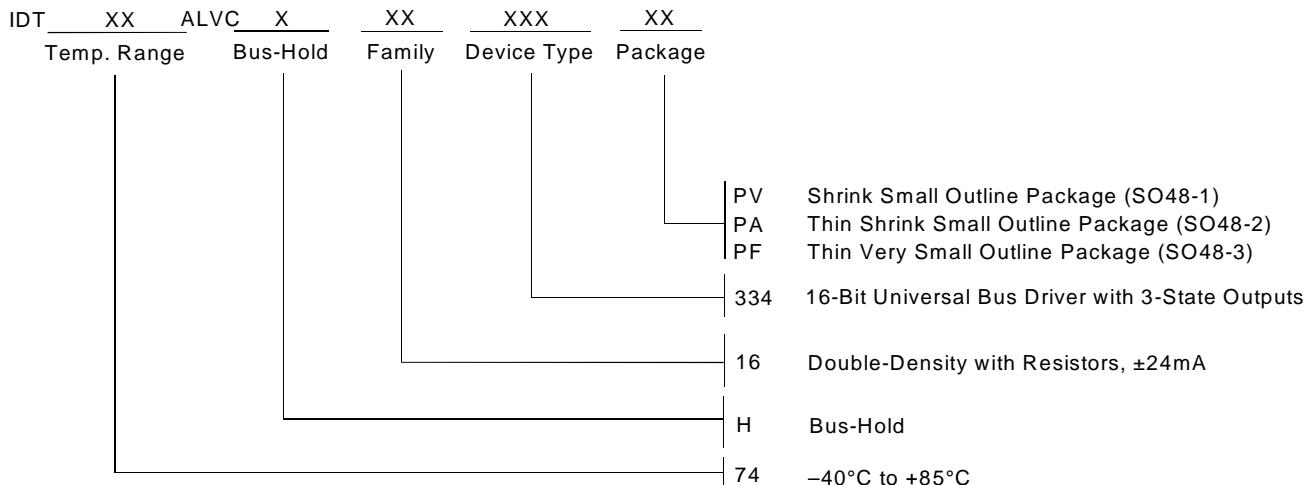
SET-UP, HOLD, AND RELEASE TIMES

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PULSE WIDTH

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